

LS320 BiFET Amplifier



Linear Systems High Input Impedance BiFET Amplifier

The LS320 is a high input impedance amplifier produced using a BiFET process and packaged in TO-92.

The TO-92 package is well suited for cost sensitive applications and mass production.

(See Packaging Information).

LS320 Features:

- High Input Impedance
- High Transconductance

| FEATURES | | | | | |
|---|----------------------------|--|--|--|--|
| HIGH INPUT IMPEDANCE | $r_{Gs} \ge = 100G\Omega$ | | | | |
| HIGH TRANSCONDUCTANCE | Y _{FS} = 30,000μS | | | | |
| ABSOLUTE MAXIMUM RATINGS ¹ @ 25°C (unless otherwise noted) | | | | | |
| Maximum Temperatures | | | | | |
| Storage Temperature | -65°C to +150°C | | | | |
| Operating Junction Temperature | -55°C to +125°C | | | | |
| Maximum Power Dissipation | | | | | |
| Continuous Power Dissipation @ +125°C | 200mW | | | | |
| Maximum Currents | 2.3mW/°C | | | | |
| Drain Current | I _D = 25mA | | | | |
| Maximum Voltages | | | | | |
| Drain to Source | $V_{DSO} = 20V$ | | | | |
| Gate to Source | V _{GSS} = 20V | | | | |

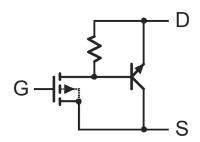
ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

| ELECTRICAL CHARACTERISTICS & 25 C (unicss otherwise noted) | | | | | | | | |
|--|----------------------------------|-------|-------------|----------|-------|--|--|--|
| SYMBOL | CHARACTERISTICS | MIN. | TYP. | MAX. | UNITS | CONDITIONS | | |
| V_{DS} | Drain to Source Voltage | -20 | | | V | $I_{DS} = 100 \mu A, V_{GS} = 0$ | | |
| V_{GS} | Collector to Source Voltage | -12 | -10 | -7 | V | $I_{DS} = 10 \text{ mA}, V_{GS} = -10 \text{ V}^{23}$ | | |
| g fs | Common Source Forward | 30000 | | | μS | | | |
| | Transconductance | | | | | $I_{DS} = 10 \text{mA}, V_{GS} = -10 \text{V}, f = 1 \text{kHz}$ | | |
| g _{oss} | Common Source Output Conductance | | 300 | | | | | |
| r_Gs | Gate to Source Input Resistance | 100 | | | GΩ | $V_{GS} = 0$ to 20V, T_J to 125°C | | |
| C _{ISS} | Input Capacitance | | 8 | | pА | $I_{DS} = 100 \mu A, V_{DS} = -10 V$ | | |
| C _{RSS} | Reverse Transfer Capacitance | " | 1. 5 | | pF | $I_{DS} = 10 \text{mA}, V_{GS} = -10 \text{V}$ | | |
| e _n | Noise Voltage | | 2 5 | / | μV | $I_{DS} = 10$ mA, $V_{DS} = 10$ V, BW = 50 to 15 kHz | | |
| | | | | | | | | |

Notes:

- 1. Absolute Maximum ratings are limiting values above which serviceability may be impaired
- 2. The gate to source voltage must never exceed 100V, t < 10ms
- 3. Additional screening available

Functional Schematic



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Available Packages:

LS320 in TO-92 LS320 in bare die.

Please contact Micross for full package and die dimensions

TO-92 (Bottom View)

